

# **P26B10SN**

# Power MOSFETs 100V, 26A, N-channel

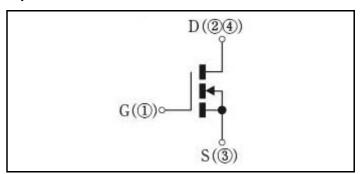
### **Feature**

- N-channel
- SMD
- Low Ron
- 10V Gate Drive
- · Low Capacitance
- · Pb free terminal
- RoHS:Yes

## **OUTLINE**



# **Equivalent circuit**



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150	°C
Drain-source voltage	$V_{DSS}$		100	٧
Gate-source voltage	$V_{GSS}$		±20	V
Continuous drain current(DC)	I <sub>D</sub>		26	Α
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10µs, duty=1/100	78	Α
Total power dissipation	P <sub>T</sub>		44	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	19	Α
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	40	mJ

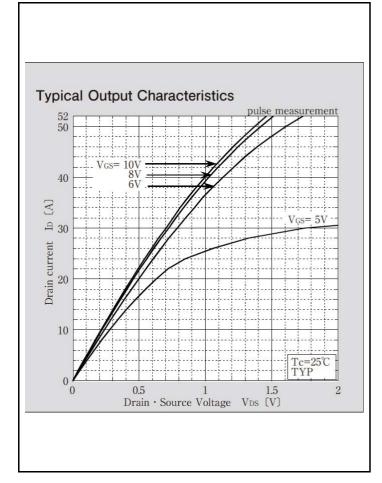
<sup>\* :</sup> See the original Specifications

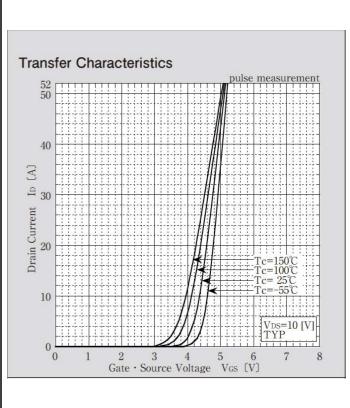
# **Electrical Characteristics** (unless otherwise specified : Tc=25°C)

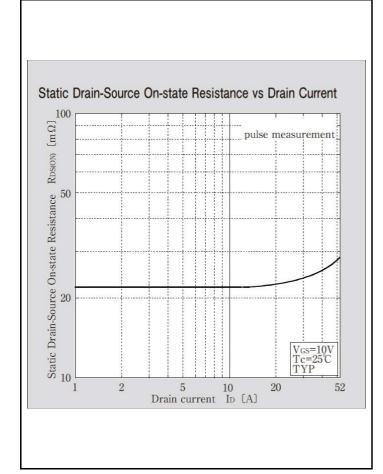
Item	Symbol	Conditions	Ratings			l lait
			MIN	TYP	MAX	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	100			٧
Zero gate voltage drain current	I <sub>DSS</sub>	VDS=100V, VGS=0V			1	μΑ
Gate-source leakage current	I <sub>GSS</sub>	VGS=±20V, VDS=0V			±0.1	μΑ
Forward transconductance	9fs	ID=13A, VDS=10V	8	16		S
Static drain-source on-state resistance	R <sub>DS(ON)</sub>	ID=13A, VGS=10V		0.022	0.028	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	$V_{SD}$	IS=26A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case			2.84	°C/W
Total gate charge	Qg	VDD=80V, VGS=10V, ID=26A		35		nC
Gate to source charge	Qgs	VDD=80V, VGS=10V, ID=26A		10		nC
Gate to drain charge	Qgd	VDD=80V, VGS=10V, ID=26A		12		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		1700		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		75		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		164		pF
Turn-on delay time	td(on)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		7		ns
Rise time	tr	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		11		ns
Turn-off delay time	td(off)	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		21		ns
Fall time	tf	ID=13A, RL=3.85Ω, VDD=50V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		6		ns
Diode reverse recovery time	trr	IF=26A, VGS=0V, di/dt=100A/μs		52		ns
Diode reverse recovery charge	Qrr	IF=26A, VGS=0V, di/dt=100A/μs		103		nC

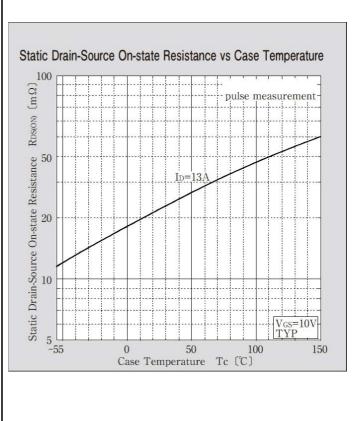
<sup>\*</sup> :See the original Specifications

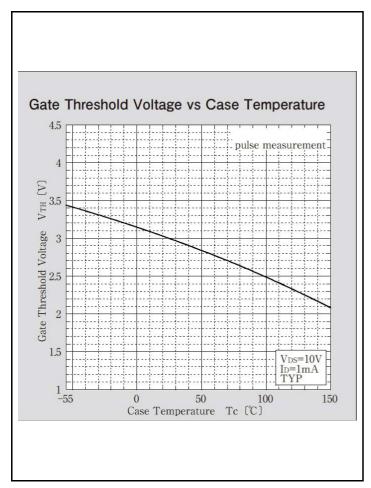
# **CHARACTERISTIC DIAGRAMS**

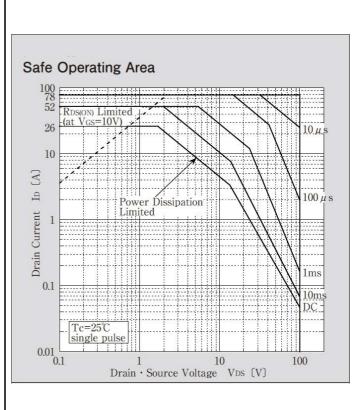


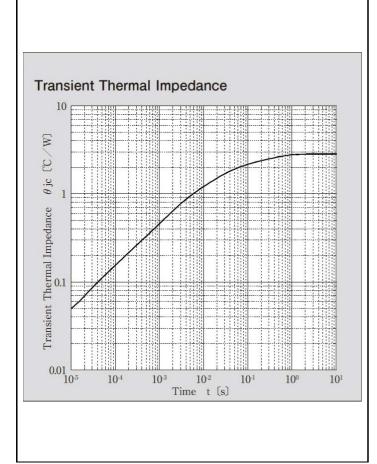


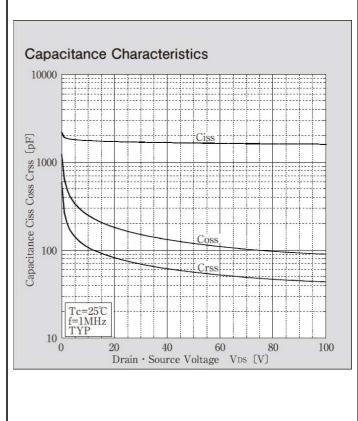


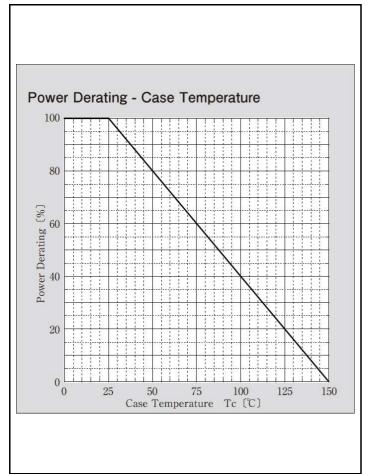


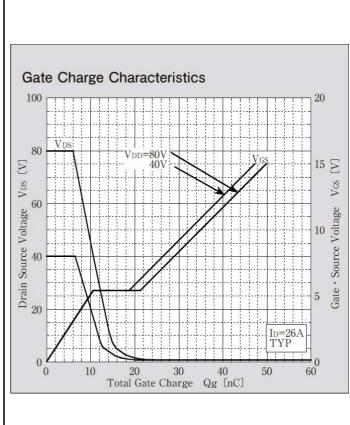


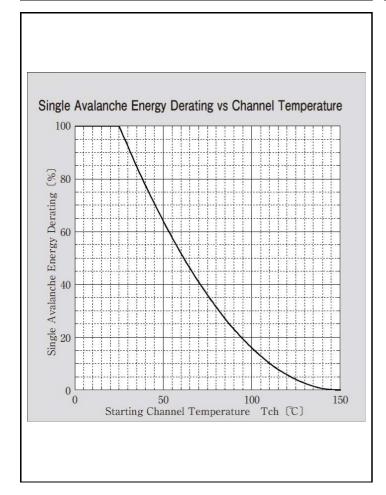






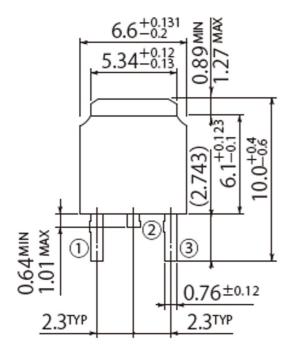


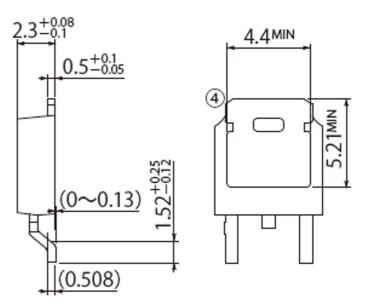


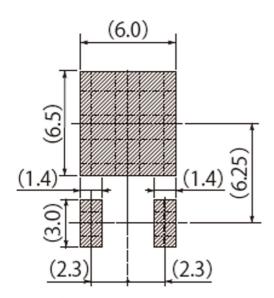


G2

JEDEC Code	TO-252AA		
JEITA Code	_		
House Name	FB		







Referential Soldering Pad

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